# NSN 5961-01-089-2664

Transistor - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

## **Overall Height:**

0.350 inches

### **Overall Width:**

1.050 inches

#### **End Application:**

An/tyq-1 (v) & an/tyq-12(v)

#### **Mounting Facility Quantity:**

2

#### **Internal Configuration:**

Junction contact-darlington connected

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Burn in and hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 collector to emitter voltage/static/base open

## **Current Rating Per Characteristic:**

20.00 amperes source cutoff current and 1.00 milliamperes zero-gate-voltage source current preset

### **Power Rating Per Characteristic:**

160.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

1 case and 2 pin

#### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

Fiig:

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